

P-Channel 20 V (D-S) MOSFET

PRODUCT SUMMARY

V_{DS} (V)	$R_{DS(on)}$ (Ω) Max.	I_D (A)	Q_g (Typ.)
- 20	0.078 at $V_{GS} = - 4.5$ V	- 1.4	12.1 nC
	0.098 at $V_{GS} = - 2.5$ V	- 1	
	0.130 at $V_{GS} = - 1.8$ V	- 1	
	0.188 at $V_{GS} = - 1.5$ V	- 0.3	

FEATURES

- TrenchFET® Power MOSFET
- Typical ESD Performance 2500 V
- 100 % R_g Tested
- Material categorization:
For definitions of compliance please see
www.vishay.com/doc?99912

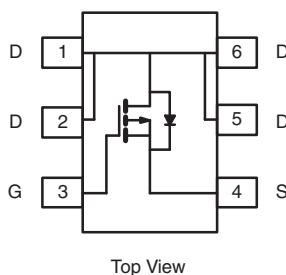


RoHS
COMPLIANT
HALOGEN
FREE

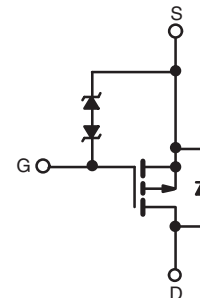
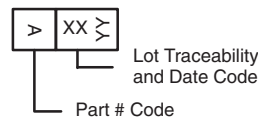
APPLICATIONS

- Load Switch for Portable Devices
- Power Management

SC-89 (6-LEADS)



Marking Code



Ordering Information: Si1077X-T1-GE3 (Lead (Pb)-free and Halogen-free)

P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS ($T_A = 25$ °C, unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V_{DS}	- 20	V
Gate-Source Voltage	V_{GS}	± 8	
Continuous Drain Current ($T_J = 150$ °C)	$T_A = 25$ °C	- 1.75 ^{b, c}	A
	$T_A = 70$ °C	- 1.4 ^{b, c}	
Pulsed Drain Current ($t = 300$ μ s)	I_{DM}	- 8	
Continuous Source-Drain Diode Current	$T_A = 25$ °C	- 0.28 ^{b, c}	
Maximum Power Dissipation	$T_A = 25$ °C	0.33 ^{b, c}	W
	$T_A = 70$ °C	0.21 ^{b, c}	
Operating Junction and Storage Temperature Range	T_J, T_{stg}	- 55 to 150	°C

THERMAL RESISTANCE RATINGS

Parameter	Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient ^{a, b}	$t \leq 5$ s	300	375	°C/W
	Steady State	360	450	

Notes:

a. Maximum under steady state conditions is 450 °C/W.

b. Surface mounted on 1" x 1" FR4 board.

c. $t = 5$ s.

SPECIFICATIONS ($T_J = 25\text{ }^{\circ}\text{C}$, unless otherwise noted)

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Static						
Drain-Source Breakdown Voltage	V _{DS}	V _{GS} = 0 V, I _D = - 250 μA	- 20			V
V _{DS} Temperature Coefficient	ΔV _{DS} /T _J	I _D = - 250 μA		- 11		mV/°C
V _{GS(th)} Temperature Coefficient	ΔV _{GS(th)} /T _J			2.4		
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = - 250 μA	- 0.4		- 1	V
Gate-Source Leakage	I _{GSS}	V _{DS} = 0 V, V _{GS} = ± 8 V			± 10	μA
		V _{DS} = 0 V, V _{GS} = ± 4.5 V			± 1	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = - 20 V, V _{GS} = 0 V			- 1	
		V _{DS} = - 20 V, V _{GS} = 0 V, T _J = 85 °C			- 10	
On-State Drain Current ^a	I _{D(on)}	V _{DS} = ≥ - 5 V, V _{GS} = - 4.5 V	- 8			A
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = - 4.5 V, I _D = - 1.8 A		0.065	0.078	Ω
		V _{GS} = - 2.5 V, I _D = - 1 A		0.081	0.098	
		V _{GS} = - 1.8 V, I _D = - 1 A		0.100	0.130	
		V _{GS} = - 1.5 V, I _D = - 0.3 A		0.125	0.188	
Forward Transconductance	g _{fs}	V _{DS} = - 10 V, I _D = - 1.8 A		10		S
Dynamic ^b						
Input Capacitance	C _{iss}	V _{DS} = - 10 V, V _{GS} = 0 V, f = 1 MHz		965		pF
Output Capacitance	C _{oss}			110		
Reverse Transfer Capacitance	C _{rss}			101		
Total Gate Charge	Q _g	V _{DS} = - 10 V, V _{GS} = - 8 V, I _D = - 1.75 A		20.7	31.1	nC
		V _{DS} = - 10 V, V _{GS} = - 4.5 V, I _D = - 1.75 A		12.1	18.2	
Gate-Source Charge	Q _{gs}			1.85		
Gate-Drain Charge	Q _{gd}			2.21		
Gate Resistance	R _g	f = 1 MHz	3.6	18	36	Ω
Turn-On Delay Time	t _{d(on)}	V _{DD} = - 10 V, R _L = 7.1 Ω I _D ≅ - 1.4 A, V _{GEN} = - 4.5 V, R _g = 1 Ω		24	36	ns
Rise Time	t _r			17	26	
Turn-Off Delay Time	t _{d(off)}			95	145	
Fall Time	t _f			28	42	
Turn-On Delay Time	t _{d(on)}	V _{DD} = - 10 V, R _L = 7.1 Ω I _D = - 1.4 A, V _{GEN} = - 8 V, R _g = 1 Ω		5	10	ns
Rise Time	t _r			8	16	
Turn-Off Delay Time	t _{d(off)}			115	173	
Fall Time	t _f			26	39	
Drain-Source Body Diode Characteristics						
Pulse Diode Forward Current ^a	I _{SM}				- 8	A
Body Diode Voltage	V _{SD}	I _S = - 1.4 A		- 0.75	- 1.2	V
Body Diode Reverse Recovery Time	t _{rr}	I _F = - 1.4 A, dI/dt = 100 A/μs		16	24	ns
Body Diode Reverse Recovery Charge	Q _{rr}			7	14	nC
Reverse Recovery Fall Time	t _a			9		ns
Reverse Recovery Rise Time	t _b			7		

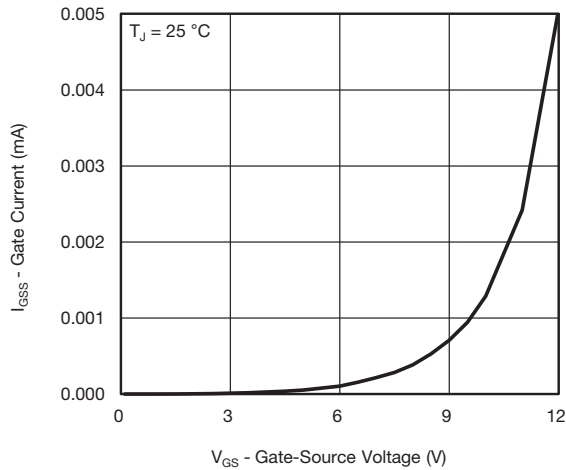
Notes:

a. Pulse test; pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$.

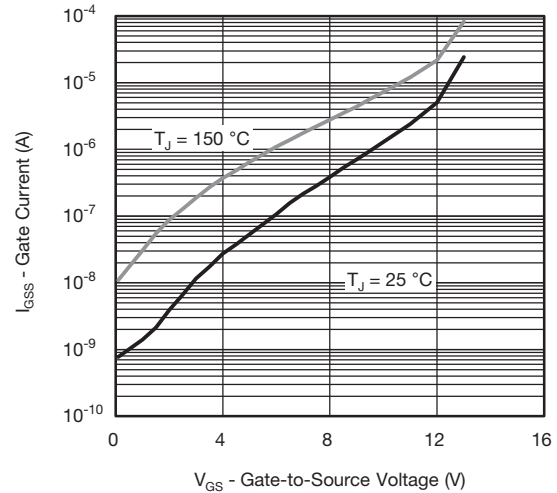
b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

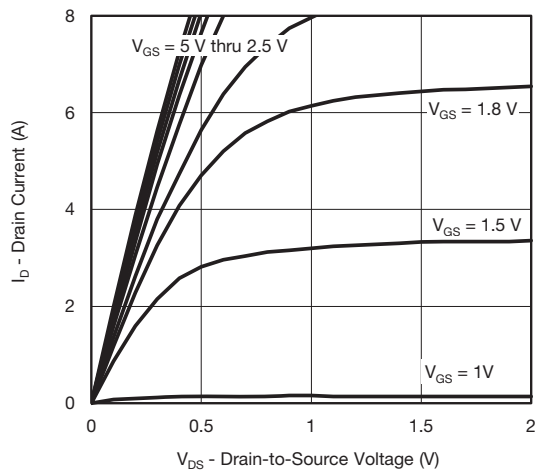
TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$, unless otherwise noted)



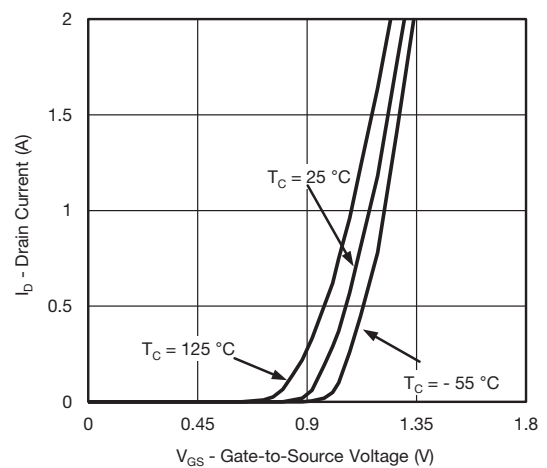
Gate Current vs. Gate-Source Voltage



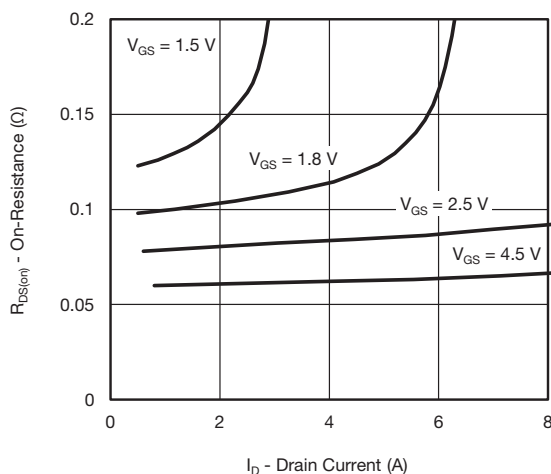
Gate Current vs. Gate-to-Source Voltage



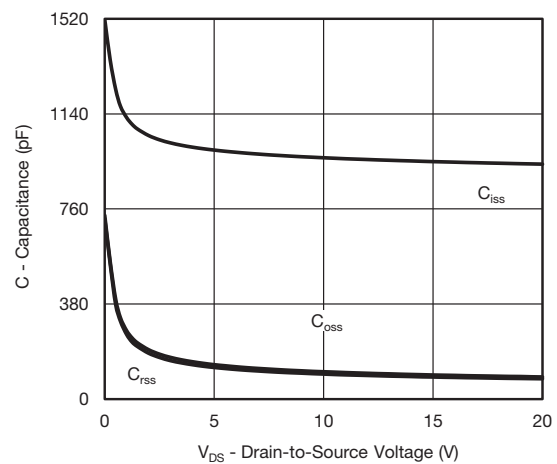
Output Characteristics



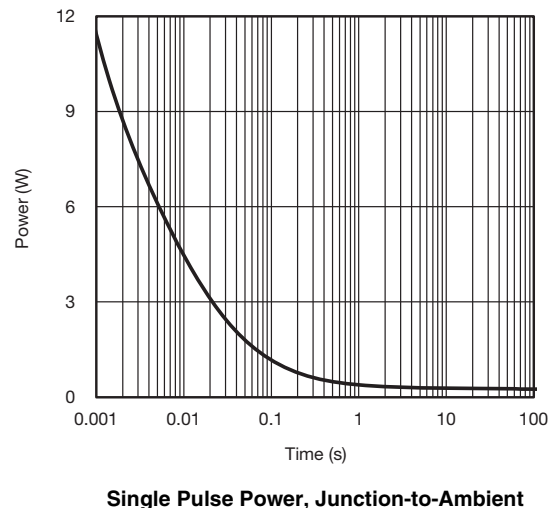
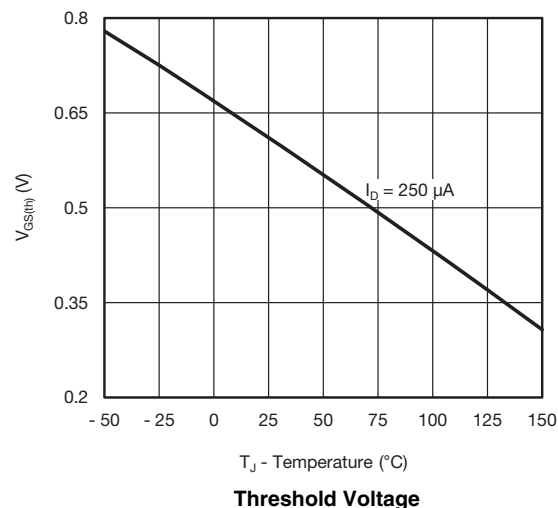
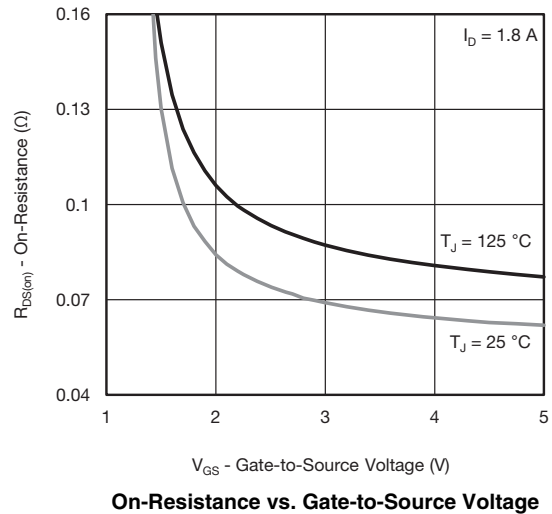
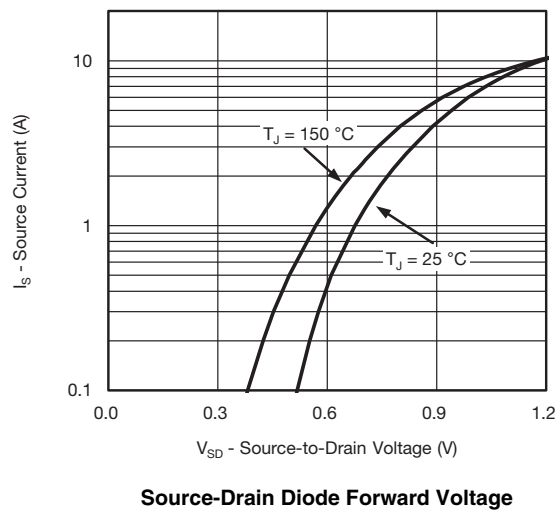
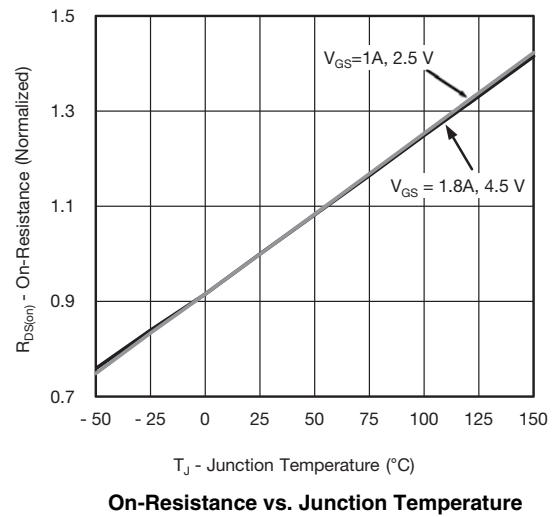
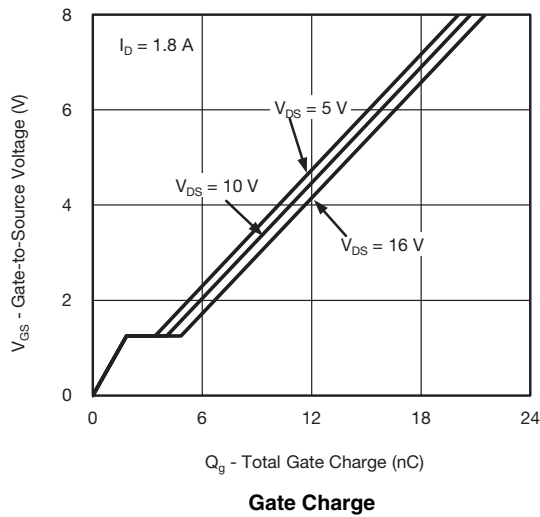
Transfer Characteristics Curves vs. Temperature



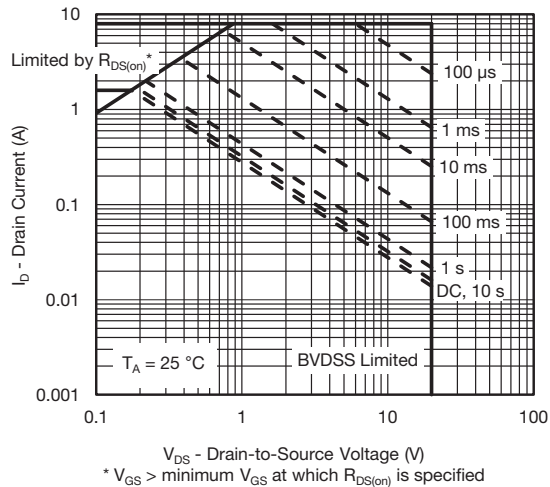
On-Resistance vs. Drain Current



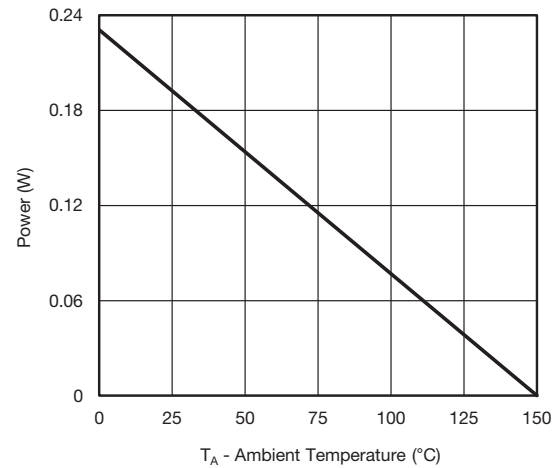
Capacitance

TYPICAL CHARACTERISTICS ($T_A = 25\text{ }^{\circ}\text{C}$, unless otherwise noted)


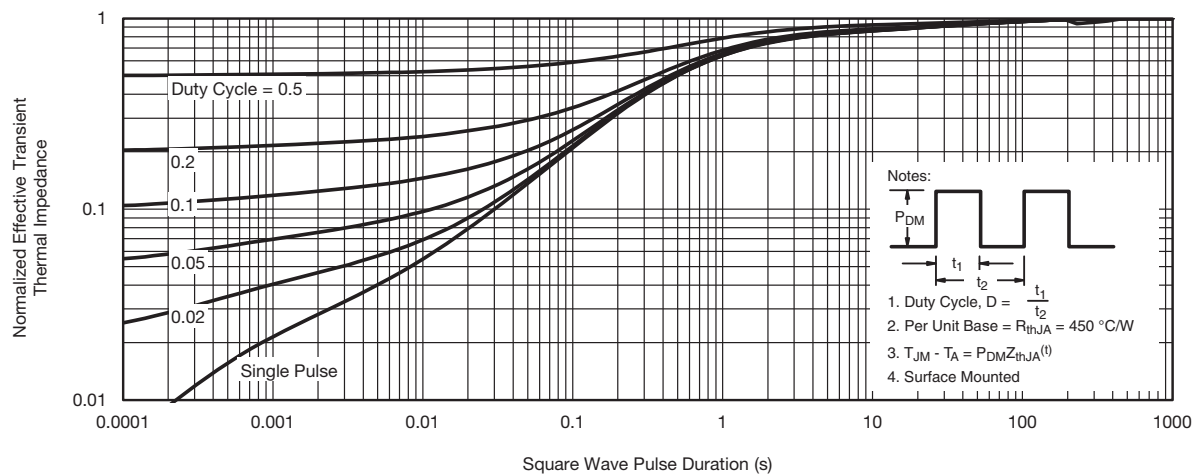
TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$, unless otherwise noted)



Safe Operating Area, Junction-to-Ambient



Power Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Ambient

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SC-89 6-Leads (SOT-563F)



Notes

1. Dimensions in millimeters.
2. Dimension D does not include mold flash, protrusions or gate burrs. Mold flash, protrusions or gate burrs shall not exceed 0.15 mm per dimension E1 does not include interlead flash or protrusion, interlead flash or protrusion shall not exceed 0.15 mm per side.
3. Dimensions D and E1 are determined at the outmost extremes of the plastic body exclusive of mold flash, the bar burrs, gate burrs and interlead flash, but including any mismatch between the top and the bottom of the plastic body.
4. Datums A, B and D to be determined 0.10 mm from the lead tip.
5. Terminal numbers are shown for reference only.
6. These dimensions apply to the flat section of the lead between 0.08 mm and 0.15 mm from the lead tip.

DIM.	MILLIMETERS		
	MIN.	NOM.	MAX.
A	0.56	0.58	0.60
A1	0	0.02	0.10
b	0.15	0.22	0.30
c	0.10	0.14	0.18
D	1.50	1.60	1.70
E	1.50	1.60	1.70
E1	1.15	1.20	1.25
e	0.45	0.50	0.55
e1	0.95	1.00	1.05
L	0.25	0.35	0.50
L1	0.10	0.20	0.30

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DWG: 5880

RECOMMENDED MINIMUM PADS FOR SC-89: 6-Lead



Recommended Minimum Pads
Dimensions in Inches/(mm)

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Телефон: +7 812 627 14 35

Электронная почта: sales@st-electron.ru

Адрес: 198099, Санкт-Петербург,
Промышленная ул, дом № 19, литера Н,
помещение 100-Н Офис 331